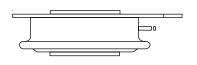


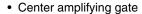
Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 500 A

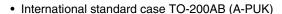


TO-200AB (A-PUK)

FEATURES









• Lead (Pb)-free



ROHS COMPLIANT

| PRODUCT SUMMARY | | | | |
|--------------------|-------|--|--|--|
| I _{T(AV)} | 500 A | | | |

TYPICAL APPLICATIONS

- · DC motor controls
- Controlled DC power supplies
- · AC controllers

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|------------------------------------|-----------------|-------------|-------------------|--|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | | |
| 1 | | 500 | А | | | |
| I _{T(AV)} | T _{hs} | 80 | °C | | | |
| 1 | | 1130 | A | | | |
| I _{T(RMS)} | T _{hs} | 25 | °C | | | |
| I _{TSM} | 50 Hz | 7200 | ۸ | | | |
| | 60 Hz | 7500 | Α | | | |
| I ² t | 50 Hz | 260 | kA ² s | | | |
| 1-1 | 60 Hz | 230 | KA-S | | | |
| V _{DRM} /V _{RRM} | | 400 to 600 | V | | | |
| tq | Typical | 100 | μѕ | | | |
| T _J | | - 40 to 150 | °C | | | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | | | |
|-----------------|-----------------|---|--|---|--|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V | I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA | | | | |
| ST280CHC | 04 | 400 | 500 | 75 | | | | |
| 06 O6 | | 600 | 700 | 75 | | | | |

ST280CHPbF Series

Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 500 A



| ABSOLUTE MAXIMUM RATIN | GS | | | | | |
|---|---------------------|--|---|-----------------------------------|------------|---------------------|
| PARAMETER | SYMBOL | | TEST CONDITIONS | | | UNITS |
| Maximum average on-state current | - | 180° condu | ction, half sine v | vave | 500 (185) | Α |
| at heatsink temperature | I _{T(AV)} | double side | (single side) co | oled | 80 (110) | °C |
| Maximum RMS on-state current | I _{T(RMS)} | DC at 25 °C | heatsink tempe | erature double side cooled | 1130 | |
| | | t = 10 ms | No voltage | | 7200 | |
| Maximum peak, one-cycle | ı | t = 8.3 ms | reapplied | | 7500 | A |
| non-repetitive surge current | I _{TSM} | t = 10 ms | 100 % V _{RRM} | | 6000 | |
| | | t = 8.3 ms | reapplied | Sinusoidal half wave, | 6300 | |
| Maximum I ² t for fusing | l ² t | t = 10 ms | No voltage reapplied | initial $T_J = T_J$ maximum | 260 | - kA ² s |
| | | t = 8.3 ms | | | 235 | |
| | | t = 10 ms | | | 180 | |
| | | t = 8.3 ms | reapplied | | 165 | |
| Maximum I ² √t for fusing | I ² √t | t = 0.1 to 10 | t = 0.1 to 10 ms, no voltage reapplied | | | kA²√s |
| Low level value of threshold voltage | V _{T(TO)1} | (16.7 % x π | $x I_{T(AV)} < I < \pi x$ | $I_{T(AV)}$, $T_J = T_J$ maximum | 0.84 | V |
| High level value of threshold voltage | V _{T(TO)2} | $(I > \pi \times I_{T(AV)})$ | $(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$ | | | V |
| Low level value of on-state slope resistance | r _{t1} | (16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum | | | 0.50 | mΩ |
| High level value of on-state slope resistance | r _{t2} | $(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$ | | | 0.47 | 1115.2 |
| Maximum on-state voltage | V_{TM} | $I_{pk} = 1000 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$ | | | 1.35 | V |
| Maximum holding current | lΗ | T _J = 25 °C, anode supply 12 V resistive load | | | 600 | mΛ |
| Maximum (typical) latching current | IL | 1]=25 °C, | anoue supply I | z v resistive idau | 1000 (300) | - mA |

| SWITCHING | | | | |
|--|----------------|--|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum non-repetitive rate of rise of turned-on current | dl/dt | Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$ | 1000 | A/µs |
| Typical delay time | t _d | Gate current 1 A, $dl_g/dt = 1$ A/ μ s V_d 0.67 % V_{DRM} , $T_J = 25$ °C | 1.0 | - 10 |
| Typical turn-off time | tq | $I_{TM} = 300 \text{ A, } T_J = T_J \text{ maximum, } dI/dt = 20 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, } dV/dt = 20 \text{ V/}\mu\text{s, } \text{gate } 0 \text{ V } 100 \Omega\text{, } t_p = 500 \mu\text{s}$ | 100 | μs |

| BLOCKING | | | | | | |
|--|--|--|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum critical rate of rise of off-state voltage | dV/dt | $T_J = T_J$ maximum linear to 80 % rated V_{DRM} | 500 | V/µs | | |
| Maximum peak reverse and off-state leakage current | I _{RRM} , I _{DRM} | $T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied | 75 | mA | | |





Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 500 A

| TRIGGERING | | | | | | |
|-------------------------------------|-------------------------|-----------------------------|---|------|--------|-------|
| PARAMETER | SYMBOL | TE | TEST COMPITIONS | | VALUES | |
| PARAMETER | STINIBUL | '5 | EST CONDITIONS | TYP. | MAX. | UNITS |
| Maximum peak gate power | P_{GM} | $T_J = T_J$ maximum, | $t_p \le 5 \text{ ms}$ | 10 | 0.0 | W |
| Maximum average gate power | P _{G(AV)} | $T_J = T_J$ maximum, | f = 50 Hz, d% = 50 | 2 | .0 | VV |
| Maximum peak positive gate current | I _{GM} | $T_J = T_J$ maximum, | $t_p \le 5 \text{ ms}$ | 3 | .0 | Α |
| Maximum peak positive gate voltage | + V _{GM} | 20 | | :0 | V | |
| Maximum peak negative gate voltage | - V _{GM} | ij= ijinaximum, | $T_J = T_J$ maximum, $t_p \le 5$ ms | | | V |
| DC gate current required to trigger | I _{GT} | T _J = - 40 °C | | 180 | - | |
| | | T _J = 25 °C | Maximum required gate trigger/ | 90 | 150 | mA |
| | | T _J = 150 °C | | | - | |
| | | T _J = - 40 °C | | | - | |
| DC gate voltage required to trigger | V_{GT} | T _J = 25 °C | 12 V anode to cathode applied | 1.8 | 3.0 | V |
| | T _J = 150 °C | | 1.0 | - | | |
| DC gate current not to trigger | I _{GD} | T - T mavimum | Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied | 10 | | mA |
| DC gate voltage not to trigger | V _{GD} | $T_J = T_J \text{ maximum}$ | | 0.30 | | V |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|---|-------------|--------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum operating junction and storage temperature range | T _J , T _{Stg} | | - 40 to 150 | °C | | |
| Maximum thermal resistance, | | DC operation single side cooled | 0.17 | | | |
| junction to heatsink | R _{thJ-hs} | DC operation double side cooled | 0.08 | K/W | | |
| Maximum thermal resistance, | В | DC operation single side cooled | 0.033 | IN/VV | | |
| case to heatsink | R _{thC-hs} | DC operation double side cooled | 0.017 | | | |
| Mounting force, ± 10 % | | | 4900 | N | | |
| Wodning force, ± 10 /6 | | | (500) | (kg) | | |
| Approximate weight | | | 50 | g | | |
| Case style | | See dimensions - link at the end of datasheet | TO-200AB (A | A-PUK) | | |

| △R _{thJ-hs} CONDUCTION | | | | | | | |
|---------------------------------|-----------------------|-------------|------------------------|-------------|---------------------|-------|--|
| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | | RECTANGULAR CONDUCTION | | TEST CONDITIONS | UNITS | |
| CONDUCTION ANGLE | SINGLE SIDE | DOUBLE SIDE | SINGLE SIDE | DOUBLE SIDE | TEST CONDITIONS | UNITS | |
| 180° | 0.016 | 0.017 | 0.011 | 0.011 | $T_J = T_J$ maximum | | |
| 120° | 0.019 | 0.019 | 0.019 | 0.019 | | | |
| 90° | 0.024 | 0.024 | 0.026 | 0.026 | | K/W | |
| 60° | 0.035 | 0.035 | 0.036 | 0.037 | | | |
| 30° | 0.060 | 0.060 | 0.060 | 0.061 | | | |

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 500 A



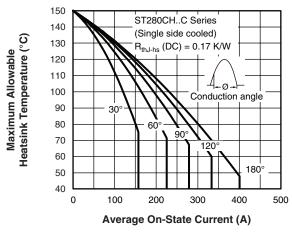


Fig. 1 - Current Ratings Characteristics

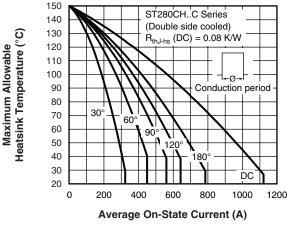


Fig. 4 - Current Ratings Characteristics

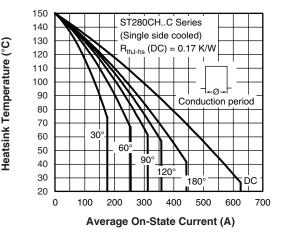


Fig. 2 - Current Ratings Characteristics

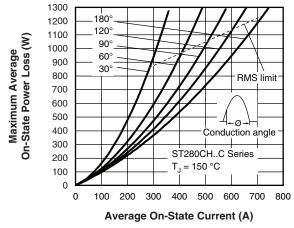


Fig. 5 - On-State Power Loss Characteristics

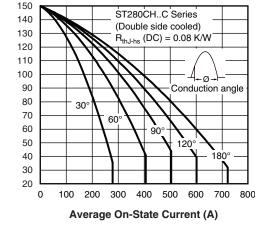


Fig. 3 - Current Ratings Characteristics

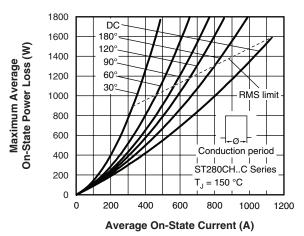


Fig. 6 - On-State Power Loss Characteristics

Heatsink Temperature ($^\circ$ C)

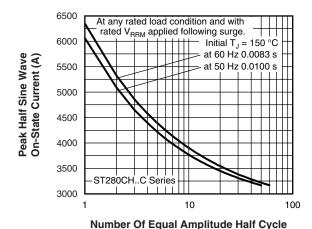
Maximum Allowable

Maximum Allowable





Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 500 A



Current Pulses (N)
Fig. 7 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

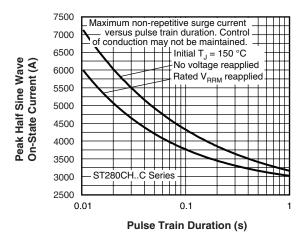


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

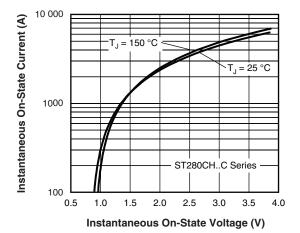


Fig. 9 - On-State Voltage Drop Characteristics

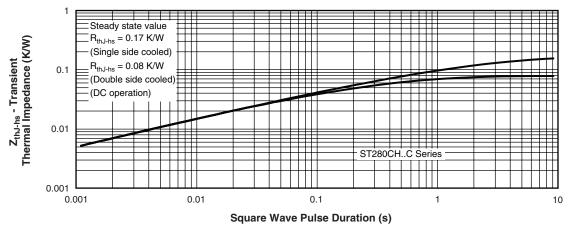


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

ST280CHPbF Series

Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 500 A



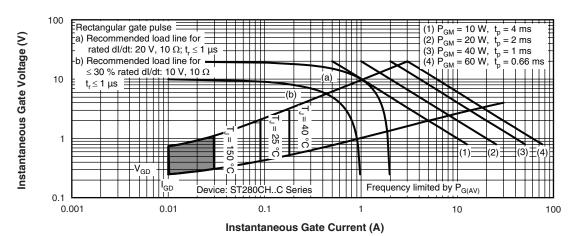
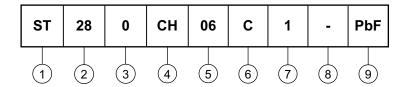


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



Thyristor

Essential part number

0 = Converter grade

CH = Ceramic PUK, high temperature

Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

C = PUK case TO-200AB (A-PUK)

0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = Eyelet terminals (gate and auxiliary cathode soldered leads)

3 = Fast-on terminals (gate and auxiliary cathode soldered leads)

8 Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

9 Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|---------------------------------|--|--|--|
| Dimensions | http://www.vishay.com/doc?95074 | | | |



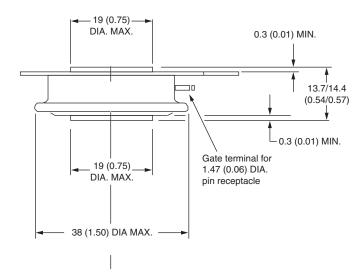
Vishay Semiconductors

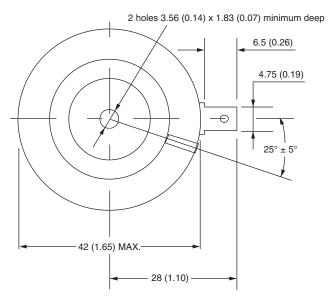
TO-200AB (A-PUK)

DIMENSIONS in millimeters (inches)

Anode to gate

Creepage distance: 7.62 (0.30) minimum Strike distance: 7.12 (0.28) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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